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# 2SA1943/FJL4215 **PNP Epitaxial Silicon Transistor**

### **Applications**

- · High-Fidelity Audio Output Amplifier
- General Purpose Power Amplifier

#### **Features**

- High Current Capability: I<sub>C</sub> = -17A.
- High Power Dissipation: 150watts.
- High Frequency: 30MHz.
- High Voltage : V<sub>CEO</sub>= -250V
- · Wide S.O.A for reliable operation.
- · Excellent Gain Linearity for low THD.
- Complement to 2SC5200/FJL4315.
- Full thermal and electrical Spice models are available.
- Same transistor is also available in:
  - -- TO3P package, 2SA1962/FJA4213: 130 watts
  - -- TO220 package, FJP1943: 80 watts
  - -- TO220F package, FJPF1943: 50 watts



1.Base 2.Collector 3.Emitter

### Absolute Maximum Ratings\* Ta = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units	
BV <sub>CBO</sub>	Collector-Base Voltage	-250	V	
BV <sub>CEO</sub>	Collector-Emitter Voltage	-250	V	
BV <sub>EBO</sub>	Emitter-Base Voltage	-5	V	
I <sub>C</sub>	Collector Current	-17	Α	
I <sub>B</sub>	Base Current	-1.5	Α	
$P_{D}$	Total Device Dissipation(T <sub>C</sub> =25°C) Derate above 25°C	150 1.04	W W/°C	
T <sub>J</sub> , T <sub>STG</sub>	Junction and Storage Temperature	- 50 ~ +150	°C	

<sup>\*</sup> These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

### Thermal Characteristics\* T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Max.	Units	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	0.83	°C/W	

<sup>\*</sup> Device mounted on minimum pad size

### **h**<sub>FE</sub> Classification

Classification	R	0
h <sub>FE1</sub>	55 ~ 110	80 ~ 160

### $\textbf{Electrical Characteristics*} \ \, \textbf{T}_{a}\text{=-}25^{\circ}\text{C unless otherwise noted}$

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> =-5mA, I <sub>E</sub> =0	-250			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> =-10mA, R <sub>BE</sub> =∞	-250			٧
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> =-5mA, I <sub>C</sub> =0	-5			V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> =-230V, I <sub>E</sub> =0			-5.0	μА
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB}$ =-5V, $I_{C}$ =0			-5.0	μΑ
h <sub>FE1</sub>	DC Current Gain	V <sub>CE</sub> =-5V, I <sub>C</sub> =-1A	55		160	
h <sub>FE2</sub>	DC Current Gain	V <sub>CE</sub> =-5V, I <sub>C</sub> =-7A	35	60		
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =-8A, I <sub>B</sub> =-0.8A		-0.4	-3.0	٧
V <sub>BE</sub> (on)	Base-Emitter On Voltage	V <sub>CE</sub> =-5V, I <sub>C</sub> =-7A		-1.0	-1.5	٧
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> =-5V, I <sub>C</sub> =-1A		30		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =-10V, f=1MHz		360		pF

<sup>\*</sup> Pulse Test: Pulse Width=20 $\mu$ s, Duty Cycle≤2%

### **Ordering Information**

Part Number	Marking	Package	Packing Method	Remarks
2SA1943RTU	A1943R	TO-264	TUBE	hFE1 R grade
2SA1943OTU	A1943O	TO-264	TUBE	hFE1 O grade
FJL4215RTU	J4215R	TO-264	TUBE	hFE1 R grade
FJL4215OTU	J4215O	TO-264	TUBE	hFE1 O grade

# **Typical Characteristics**

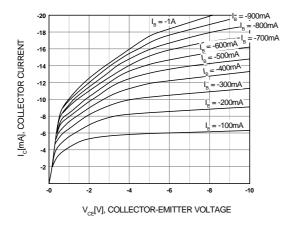


Figure 1. Static Characteristic

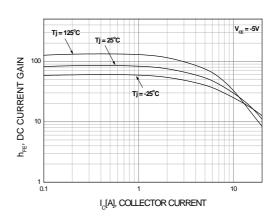


Figure 2. DC current Gain ( R Grade )



Figure 3. DC current Gain (O Grade)

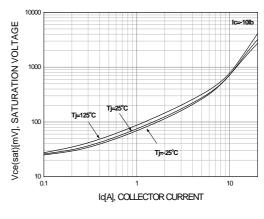


Figure 4. Collector-Emitter Saturation Voltage

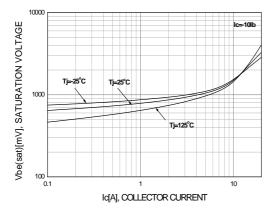


Figure 5. Base-Emitter Saturation Voltage

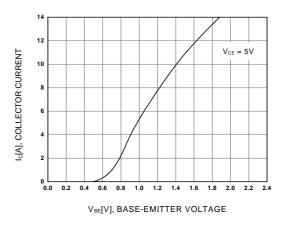


Figure 6. Base-Emitter On Voltage

### **Typical Characteristics**

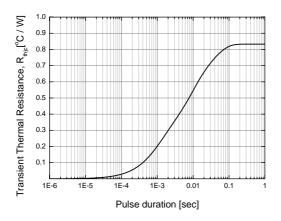


Figure 7. Thermal Resistance

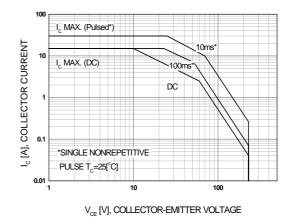


Figure 8. Safe Operating Area

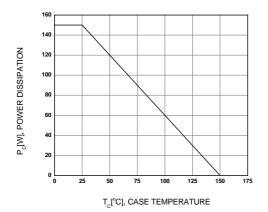
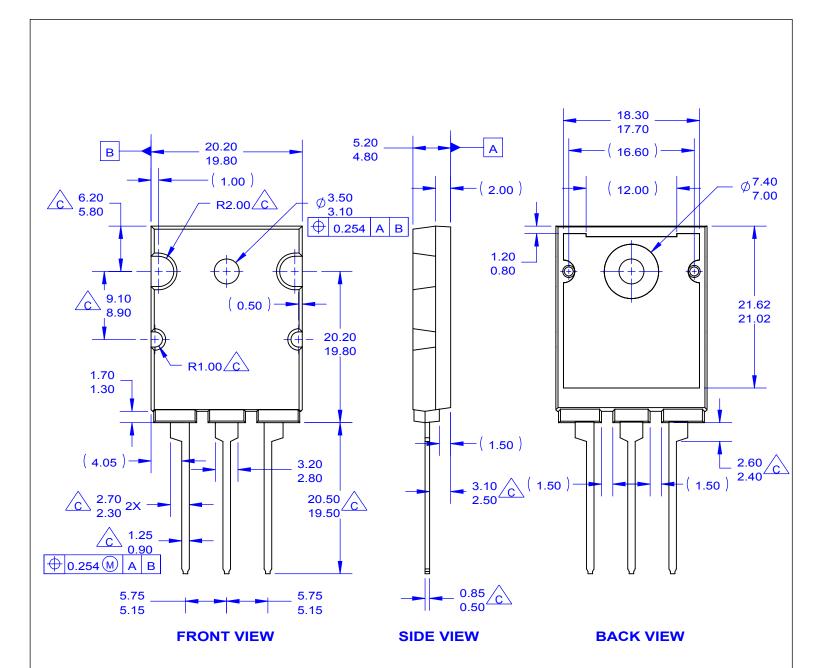
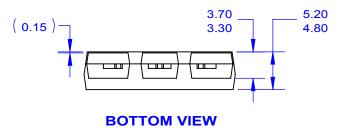


Figure 9. Power Derating







### NOTES:

- A. PACKAGE REFERENCE: JEDEC TO264 VARIATION AA.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C OUT OF JEDEC STANDARD VALUE.
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- E. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS.
- F. THIS PACKAGE IS INTENDED ONLY FOR "FS PKG CODE AR"
- G. DRAWING FILE NAME: TO264A03REV2

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